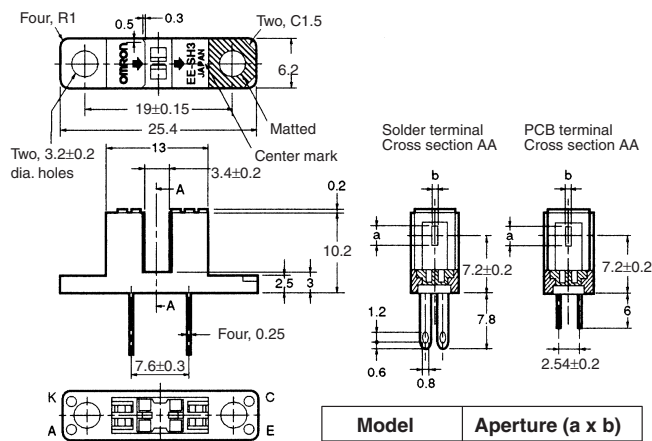


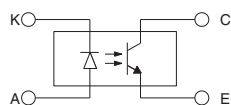
# Photomicrosensor (Transmissive) EE-SH3 Series

## ■ Dimensions

**Note:** All units are in millimeters unless otherwise indicated.



### Internal Circuit



Unless otherwise specified, the tolerances are as shown below.

Dimensions	Tolerance
3 mm max.	±0.2
3 < mm ≤ 6	±0.24
6 < mm ≤ 10	±0.29
10 < mm ≤ 18	±0.35
18 < mm ≤ 30	±0.42

Terminal No.	Name
A	Anode
K	Cathode
C	Collector
E	Emitter

## ■ Features

- High-resolution model with a 0.2-mm-wide or 0.5-mm-wide sensing aperture, high-sensitivity model with a 1-mm-wide sensing aperture, and model with a horizontal sensing aperture are available.
- Solder terminal models: EE-SH3/-SH3-CS/-SH3-DS/-SH3-GS
- PCB terminal models: EE-SH3-B/-SH3-C/-SH3-D/-SH3-G
- RoHS Compliant.

## ■ Absolute Maximum Ratings (Ta = 25°C)

Item	Symbol	Rated value
Emitter	Forward current	$I_F$ 50 mA (see note 1)
	Pulse forward current	$I_{FP}$ 1 A (see note 2)
	Reverse voltage	$V_R$ 4 V
Detector	Collector–Emitter voltage	$V_{CEO}$ 30 V
	Emitter–Collector voltage	$V_{ECO}$ ---
	Collector current	$I_C$ 20 mA
	Collector dissipation	$P_C$ 100 mW (see note 1)
Ambient temperature	Operating	$T_{opr}$ -25°C to 85°C
	Storage	$T_{stg}$ -30°C to 100°C
Soldering temperature	$T_{sol}$	260°C (see note 3)

**Note:** 1. Refer to the temperature rating chart if the ambient temperature exceeds 25°C.

2. The pulse width is 10  $\mu$ s maximum with a frequency of 100 Hz.
3. Complete soldering within 10 seconds.

## ■ Ordering Information

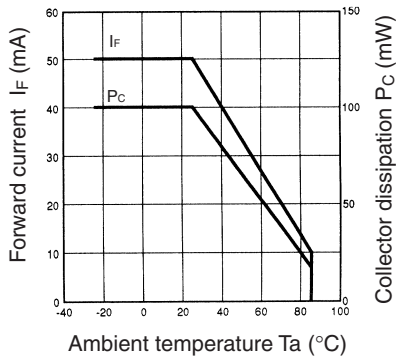
Description	Aperture (a x b)	Model
Photomicrosensor (transmissive)	2.1 x 0.5	EE-SH3(-B)
	2.1 x 1.0	EE-SH3-C(S)
	2.1 x 0.2	EE-SH3-D(S)
	0.5 x 2.1	EE-SH3-G(S)

## ■ Electrical and Optical Characteristics (Ta = 25°C)

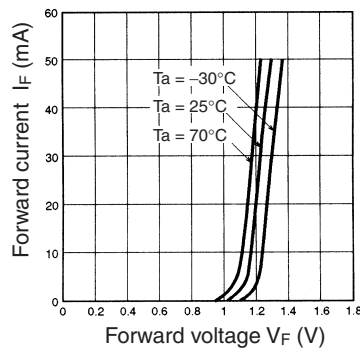
Item	Symbol	Value				Condition	
		EE-SH3(-B)	EE-SH3-C(S)	EE-SH3-D(S)	EE-SH3-G(S)		
Emitter	Forward voltage	$V_F$	1.2 V typ., 1.5 V max.			$I_F = 30$ mA	
	Reverse current	$I_R$	0.01 $\mu$ A typ., 10 $\mu$ A max.			$V_R = 4$ V	
	Peak emission wavelength	$\lambda_P$	940 nm typ.			$I_F = 20$ mA	
Detector	Light current	$I_L$	0.5 to 14 mA typ.	1 to 28 mA typ.	0.1 mA min.	0.5 to 14 mA	$I_F = 20$ mA, $V_{CE} = 10$ V
	Dark current	$I_D$	2 nA typ., 200 nA max.			$V_{CE} = 10$ V, 0 lx	
	Leakage current	$I_{LEAK}$	---			---	
	Collector–Emitter saturated voltage	$V_{CE(sat)}$	0.1 V typ., 0.4 V max.		---	0.1 V typ., 0.4 V max.	$I_F = 20$ mA, $I_L = 0.1$ mA
	Peak spectral sensitivity wavelength	$\lambda_P$	850 nm typ.			$V_{CE} = 10$ V	
Rising time	$t_r$	4 $\mu$ s typ.				$V_{CC} = 5$ V, $R_L = 100$ $\Omega$ , $I_L = 5$ mA	
Falling time	$t_f$	4 $\mu$ s typ.					

■ Engineering Data

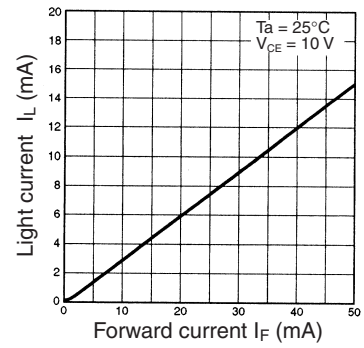
Forward Current vs. Collector Dissipation Temperature Rating



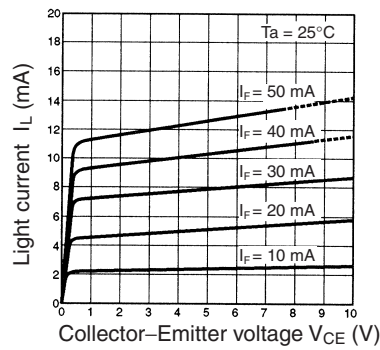
Forward Current vs. Forward Voltage Characteristics (Typical)



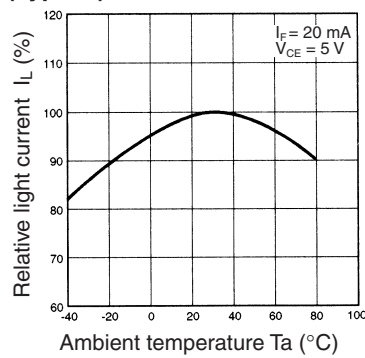
Light Current vs. Forward Current Characteristics (Typical)



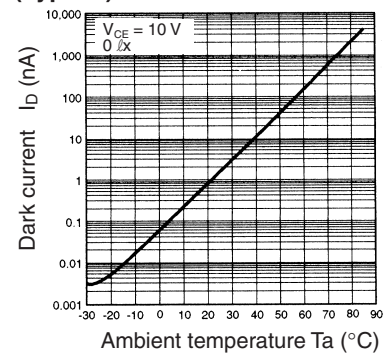
Light Current vs. Collector-Emitter Voltage Characteristics (EE-SH3(-B))



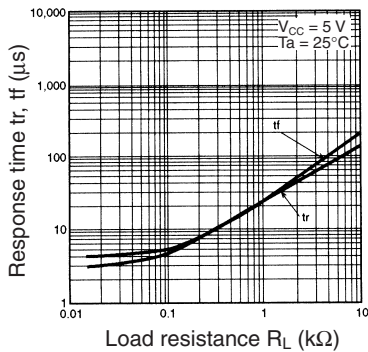
Relative Light Current vs. Ambient Temperature Characteristics (Typical)



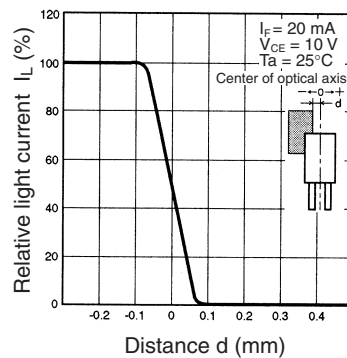
Dark Current vs. Ambient Temperature Characteristics (Typical)



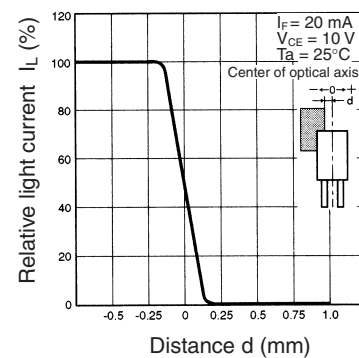
Response Time vs. Load Resistance Characteristics (Typical)



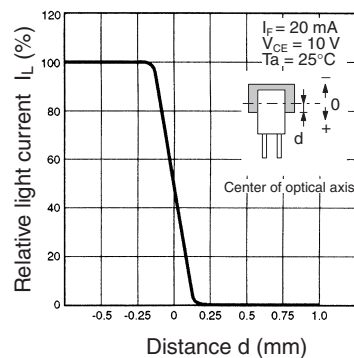
Sensing Position Characteristics (EE-SH3-D(S))



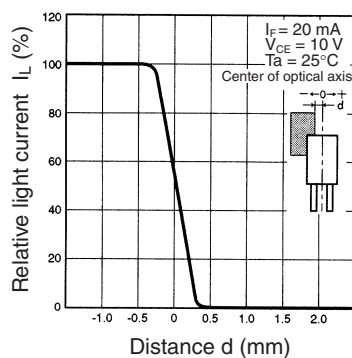
Sensing Position Characteristics (EE-SH3(-B))



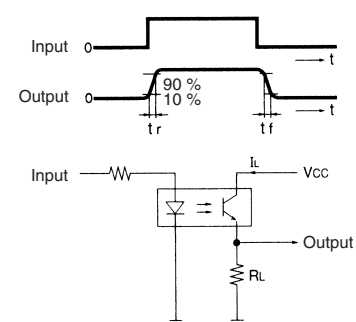
Sensing Position Characteristics (EE-SH3-G(S))



Sensing Position Characteristics (EE-SH3-C(S))



Response Time Measurement Circuit



A large grid of 20 columns and 30 rows of small squares, intended for taking notes. The grid is composed of thin, light gray lines forming a uniform pattern across the page.

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To convert millimeters into inches, multiply by 0.03937. To convert grams into ounces, multiply by 0.03527.

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